

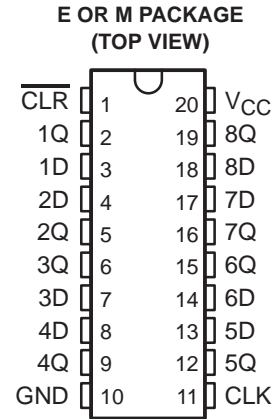
CD74FCT273

BiCMOS OCTAL D-TYPE FLIP-FLOP

WITH RESET

SCBS737A – JULY 2000 – REVISED JULY 2000

- BiCMOS Technology With Low Quiescent Power
- Buffered Inputs
- Direct Clear Input
- 48-mA Output Sink Current
- Output Voltage Swing Limited to 3.7 V
- Controlled Output Edge Rates
- Input/Output Isolation From V_{CC}
- SCR Latch-Up-Resistant BiCMOS Process and Circuit Design
- Applications Include:
 - Buffer/Storage Registers
 - Shift Registers
 - Pattern Generators
- Package Options Include Plastic Small-Outline (M) Package and Standard Plastic (E) DIP



description

The CD74FCT273 is a positive-edge-triggered, D-type flip-flop with a direct clear (\overline{CLR}) input. This device uses a small-geometry BiCMOS technology. The output stage is a combination of bipolar and CMOS transistors that limits the output high level to two diode drops below V_{CC} . This resultant lowering of output swing (0 V to 3.7 V) reduces power-bus ringing [a source of electromagnetic interference (EMI)] and minimizes V_{CC} bounce and ground bounce and their effects during simultaneous output switching. The output configuration also enhances switching speed and is capable of sinking 48 mA.

Information at the data (D) inputs meeting the setup time requirements is transferred to the Q outputs on the positive-going edge of the clock (CLK) pulse. Clock triggering occurs at a particular voltage level and is not directly related to the transition time of the positive-going pulse. When CLK is at either the high or low level, the D input has no effect at the output. All eight flip-flops are controlled by a common clock (CLK) and a common reset (\overline{CLR}). The outputs are placed in a low state when \overline{CLR} is taken low, independent of the CLK.

The CD74FCT273 is characterized for operation from 0°C to 70°C.

FUNCTION TABLE
(each flip-flop)

INPUTS			OUTPUT Q
\overline{CLR}	CLK	D	
L	X	X	L
H	↑	H	H
H	↑	L	L
H	L	X	Q_0



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**TEXAS
INSTRUMENTS**

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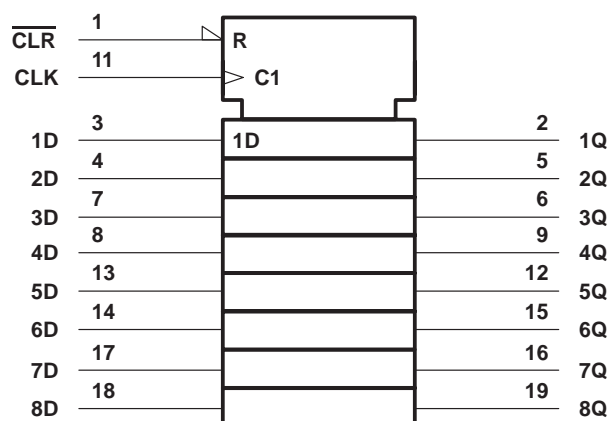
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CD74FCT273

BiCMOS OCTAL D-TYPE FLIP-FLOP WITH RESET

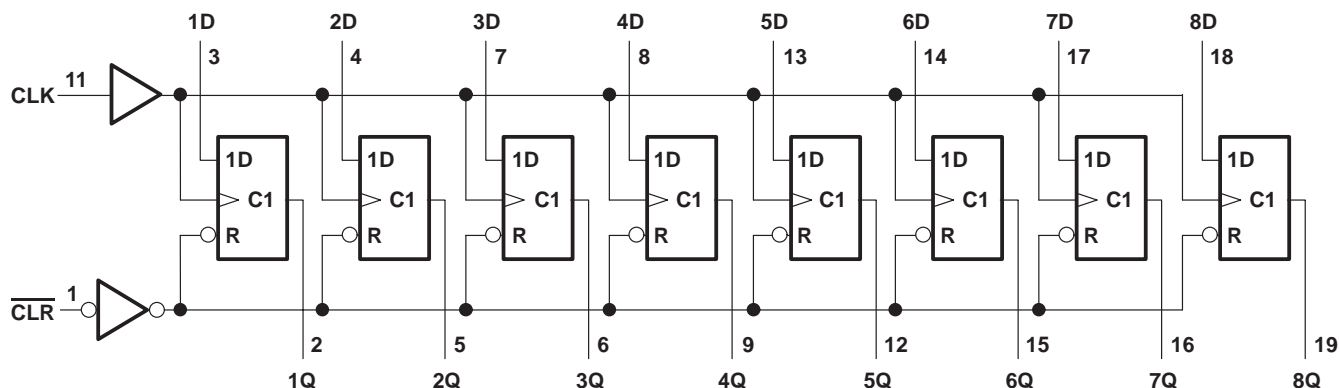
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logic symbol†

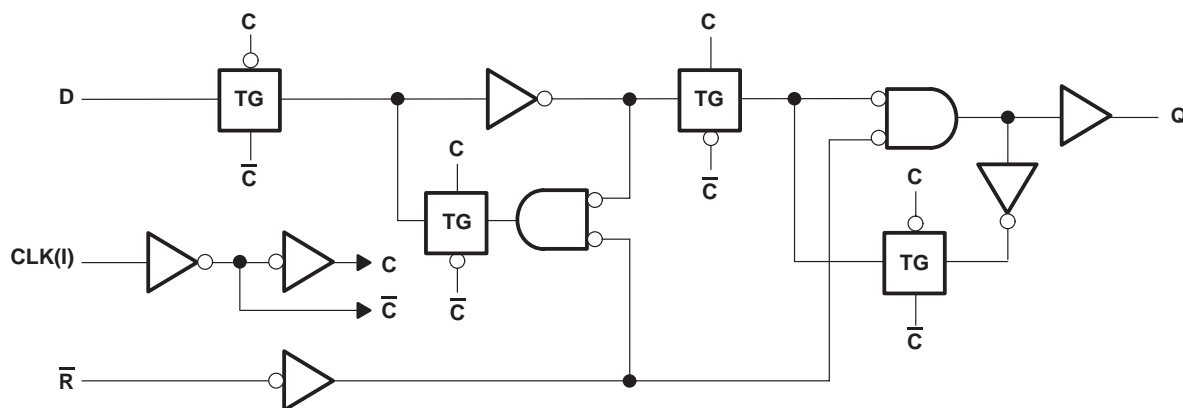


† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



logic diagram, each flip-flop (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

DC supply voltage range, V_{CC}	–0.5 V to 6 V
DC input diode current, I_{IK} ($V_I < -0.5$ V)	–20 mA
DC output diode current, I_{OK} ($V_O < -0.5$ V)	–50 mA
DC output sink current per output pin, I_{OL}	70 mA
DC output source current per output pin, I_{OH}	–30 mA
Continuous current through V_{CC} , I_{CC}	140 mA
Continuous current through GND	400 mA
Package thermal impedance, θ_{JA} (see Note 1): E package	69°C/W
M package	58°C/W
Storage temperature range, T_{stg}	–65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 2)

	MIN	MAX	UNIT
V_{CC} Supply voltage	4.75	5.25	V
V_{IH} High-level input voltage	2		V
V_{IL} Low-level input voltage		0.8	V
V_I Input voltage	0	V_{CC}	V
V_O Output voltage	0	V_{CC}	V
I_{OH} High-level output current		–15	mA
I_{OL} Low-level output current		48	mA
$\Delta t/\Delta v$ Input transition rise or fall rate	0	10	ns/V
T_A Operating free-air temperature	0	70	°C

NOTE 2: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V_{CC}	$T_A = 25^\circ\text{C}$		MIN	MAX	UNIT
			MIN	MAX			
V_{IK}	$I_I = -18$ mA	4.75 V	–1.2		–1.2		V
V_{OH}	$I_{OH} = -15$ mA	4.75 V	2.4		2.4		V
V_{OL}	$I_{OL} = 48$ mA	4.75 V		0.55		0.55	V
I_I	$V_I = V_{CC}$ or GND	5.25 V		± 0.1		± 1	μA
I_{OZ}	$V_O = V_{CC}$ or GND	5.25 V		± 0.5		± 10	μA
I_{OS}^\ddagger	$V_I = V_{CC}$ or GND, $V_O = 0$	5.25 V	–60		–60		mA
I_{CC}	$V_I = V_{CC}$ or GND, $I_O = 0$	5.25 V		8		80	μA
ΔI_{CC}^\S	One input at 3.4 V, Other inputs at V_{CC} or GND	5.25 V		1.6		1.6	mA
C_i	$V_I = V_{CC}$ or GND					10	pF

‡ Not more than one output should be tested at a time, and the duration of the test should not exceed 100 ms.

§ This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC} .

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timing requirements over recommended operating conditions (unless otherwise noted) (see Figure 1)

			MIN	MAX	UNIT
f_{clock}	Clock frequency			70	MHz
t_w	Pulse duration	$\overline{\text{CLR}}$ low	7		ns
		CLK high or low	7		
t_{su}	Setup time	Data before CLK \uparrow	3		ns
		$\overline{\text{CLR}}$ before CLK \uparrow	4		
t_h	Hold time	Data after CLK \uparrow	2		ns

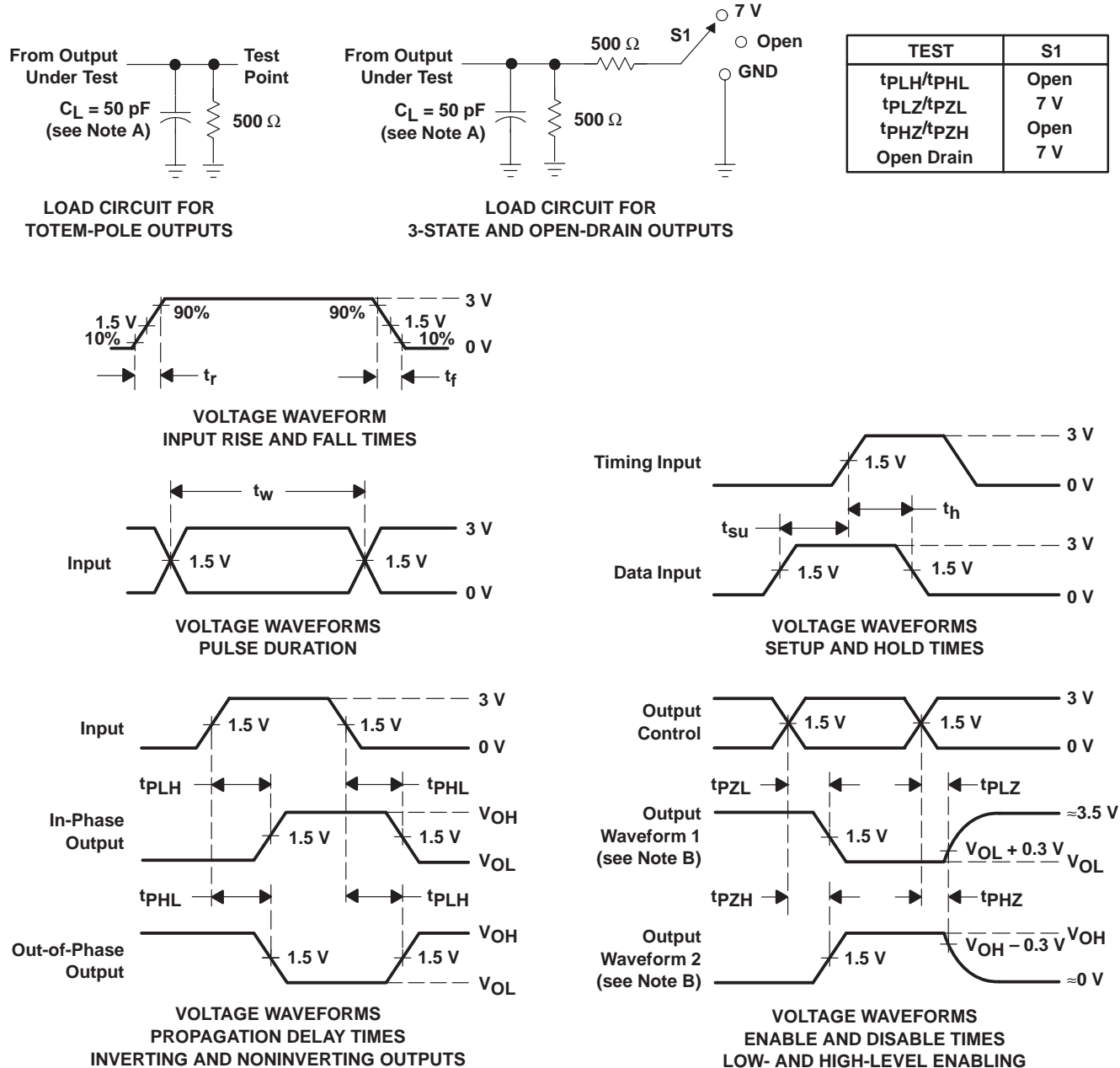
switching characteristics over recommended operating conditions, $C_L = 50$ pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$T_A = 25^\circ\text{C}$	MIN	MAX	UNIT
			TYP			
f_{max}				70		MHz
t_{pd}	CLK	Any Q	7	2	13	ns
	$\overline{\text{CLR}}$		8	2	13	

operating characteristics, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	TYP	UNIT
C_{pd}	Power dissipation capacitance	No load, $f = 1$ MHz	36	pF

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 1 \text{ MHz}$, $Z_O = 50 \Omega$, t_r and $t_f = 2.5 \text{ ns}$.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PHL} and t_{PLH} are the same as t_{pd} .

Figure 1. Load Circuit and Voltage Waveforms

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